

MC10EL35, MC100EL35

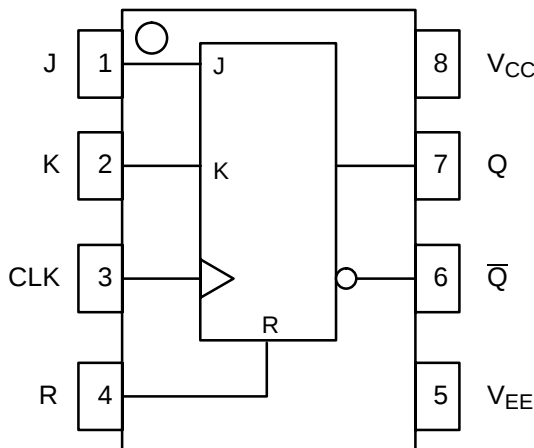
5V ECL JK Flip-Flop

The MC10EL/100EL35 is a high speed JK flip-flop. The J/K data enters the master portion of the flip-flop when the clock is LOW and is transferred to the slave, and thus the outputs, upon a positive transition of the clock. The reset pin is asynchronous and is activated with a logic HIGH.

The 100 Series contains temperature compensation.

- 525 ps Propagation Delay
- 2.2G Hz Toggle Frequency
- ESD Protection: > 1 KV HBM, > 100 V MM
- PECL Mode Operating Range: V_{CC} = 4.2 V to 5.7 with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -4.2 V to -5.7 V
- Internal Input Pulldown Resistors on J, K, CLK, and R
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8",
Oxygen Index 28 to 34
- Transistor Count = 81 devices

LOGIC DIAGRAM AND PINOUT ASSIGNMENT



PIN DESCRIPTION

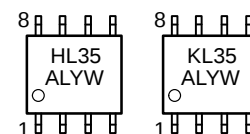
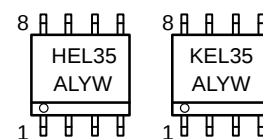
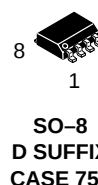
PIN	FUNCTION
J	ECL Input
K	ECL Input
R	ECL Reset
CLK	ECL Clock Input
Q, $\bar{Q}$	ECL Data Outputs
V_{CC}	Positive Supply
V_{EE}	Negative Supply



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MARKING DIAGRAMS*



H = MC10
K = MC100
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

*For additional information, see Application Note AND8002/D

TRUTH TABLE

J*	K*	R*	CLK	Qn+1
L	L	L	Z	Qn
L	H	L	Z	L
H	L	L	Z	H
H	H	L	Z	$\bar{Q}_n$
X	X	H	X	L

Z = LOW to HIGH Transition

* Pins will default low when left open.

ORDERING INFORMATION

Device	Package	Shipping
MC10EL35D	SO-8	98 Units/Rail
MC10EL35DR2	SO-8	2500 Tape & Reel
MC100EL35D	SO-8	98 Units/Rail
MC100EL35DR2	SO-8	2500 Tape & Reel
MC10EL35DT	TSSOP-8	98 Units/Rail
MC10EL35DTR2	TSSOP-8	2500 Tape & Reel
MC100EL35DT	TSSOP-8	98 Units/Rail
MC100EL35DTR2	TSSOP-8	2500 Tape & Reel

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MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		–8	V
V _I	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	V _I ≤ V _{CC} V _I ≥ V _{EE}	6 –6	V V
I _{out}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range			–40 to +85	°C
T _{stg}	Storage Temperature Range			–65 to +150	°C
θ _{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
θ _{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44 ± 5%	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

1. Maximum Ratings are those values beyond which device damage may occur.

10EL SERIES PECL DC CHARACTERISTICS V_{CC}= 5.0 V; V_{EE}= 0.0 V (Note 1.)

Symbol	Characteristic	–40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I _{EE}	Power Supply Current		27	32		27	32		27	32	mA
V _{OH}	Output HIGH Voltage (Note 2.)	3920	4010	4110	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2.)	3050	3200	3350	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage	3770		4110	3870		4190	3940		4280	mV
V _{IL}	Input LOW Voltage	3050		3500	3050		3520	3050		3555	mV
I _{IH}	Input HIGH Current			150			150			150	μA
I _{IL}	Input LOW Current	0.5			0.5			0.3			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.25 V / –0.5 V.
2. Outputs are terminated through a 50 ohm resistor to V_{CC}–2 volts.

10EL SERIES NECL DC CHARACTERISTICS V_{CC}= 0.0 V; V_{EE}= –5.0 V (Note 1.)

Symbol	Characteristic	–40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I _{EE}	Power Supply Current		27	32		27	32		27	32	mA
V _{OH}	Output HIGH Voltage (Note 2.)	–1080	–990	–890	–980	–895	–810	–910	–815	–720	mV
V _{OL}	Output LOW Voltage (Note 2.)	–1950	–1800	–1650	–1950	–1790	–1630	–1950	–1773	–1595	mV
V _{IH}	Input HIGH Voltage	–1230		–890	–1130		–810	–1060		–720	mV
V _{IL}	Input LOW Voltage	–1950		–1500	–1950		–1480	–1950		–1445	mV
I _{IH}	Input HIGH Current			150			150			150	μA
I _{IL}	Input LOW Current	0.5			0.5			0.3			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.25 V / –0.5 V.
2. Outputs are terminated through a 50 ohm resistor to V_{CC}–2 volts.

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100EL SERIES PECL DC CHARACTERISTICS $V_{CC}=5.0\text{ V}$; $V_{EE}=0.0\text{ V}$ (Note 1.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		27	32		27	32		32	37	mA
V_{OH}	Output HIGH Voltage (Note 2.)	3915	3995	4120	3975	4045	4120	3975	4050	4120	mV
V_{OL}	Output LOW Voltage (Note 2.)	3170	3305	3445	3190	3295	3380	3190	3295	3380	mV
V_{IH}	Input HIGH Voltage (Single Ended)	3835		4120	3835		4120	3835		4120	mV
V_{IL}	Input LOW Voltage (Single Ended)	3190		3525	3190		3525	3190		3525	mV
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.8 V / -0.5 V.
2. Outputs are terminated through a 50 ohm resistor to V_{CC} -2 volts.

100EL SERIES NECL DC CHARACTERISTICS $V_{CC}=0.0\text{ V}$; $V_{EE}=-5.0\text{ V}$ (Note 1.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		27	32		27	32		32	37	mA
V_{OH}	Output HIGH Voltage (Note 2.)	-1085	-1005	-880	-1025	-955	-880	-1025	-955	-880	mV
V_{OL}	Output LOW Voltage (Note 2.)	-1830	-1695	-1555	-1810	-1705	-1620	-1810	-1705	-1620	mV
V_{IH}	Input HIGH Voltage (Single Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V_{IL}	Input LOW Voltage (Single Ended)	-1810		-1475	-1810		-1475	-1810		-1475	mV
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.8 V / -0.5 V.
2. Outputs are terminated through a 50 ohm resistor to V_{CC} -2 volts.

AC CHARACTERISTICS $V_{CC}=5.0\text{ V}$; $V_{EE}=0.0\text{ V}$ or $V_{CC}=0.0\text{ V}$; $V_{EE}=-5.0\text{ V}$ (Note 1.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$f_{\max}$	Maximum Toggle Frequency	1.4	2.0		1.8	2.2		1.8	2.2		GHz
t_{PLH} t_{PHL}	Propagation Delay to Output CLK MR	290 225	515 450	740 675	350 275	525 450	700 625	395 350	570 525	745 700	ps
t_S	Setup Time J, K	150	0		150	0		150	0		ps
t_H	Hold Time J, K	250	100		250	100		250	100		ps
t_{RR}	Reset Recovery	400	200		400	200		400	200		ps
t_{PW}	Minimum Pulse Width CLK, Reset	400			400			400			ps
t_{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t_r t_f	Output Rise/Fall Times Q (20% – 80%)	100	225	350	100	225	350	100	225	350	ps

1. 10 Series: V_{EE} can vary +0.25 V / -0.5 V.
100 Series: V_{EE} can vary +0.8 V / -0.5 V.

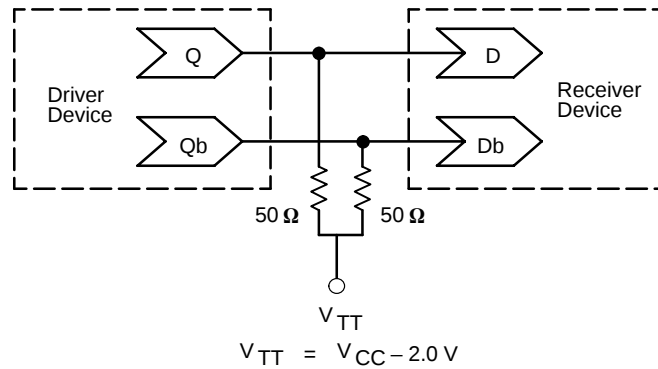


Figure 1. Typical Termination for Output Driver and Device Evaluation
 (See Application Note AND8020 – Termination of ECL Logic Devices.)

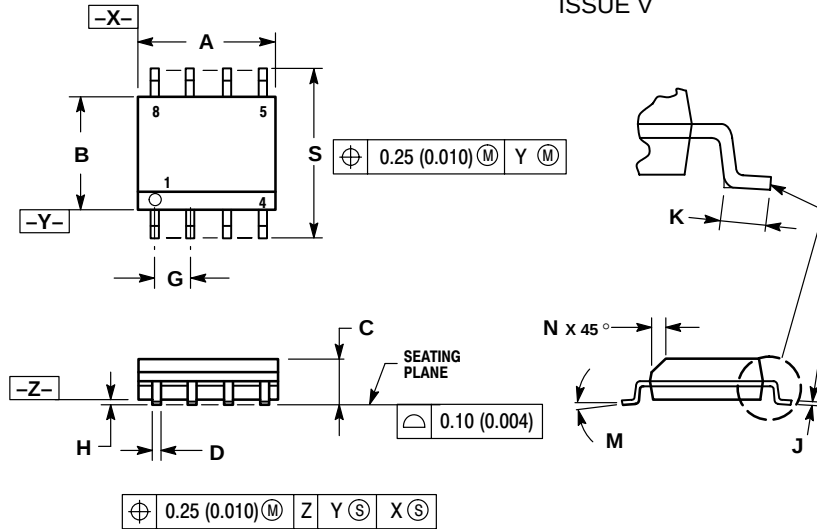
Resource Reference of Application Notes

- AN1404** – ECLinPS Circuit Performance at Non–Standard V_{IH} Levels
- AN1405** – ECL Clock Distribution Techniques
- AN1406** – Designing with PECL (ECL at +5.0 V)
- AN1503** – ECLinPS I/O SPICE Modeling Kit
- AN1504** – Metastability and the ECLinPS Family
- AN1560** – Low Voltage ECLinPS SPICE Modeling Kit
- AN1568** – Interfacing Between LVDS and ECL
- AN1596** – ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
- AN1650** – Using Wire–OR Ties in ECLinPS Designs
- AN1672** – The ECL Translator Guide
- AND8001** – Odd Number Counters Design
- AND8002** – Marking and Date Codes
- AND8020** – Termination of ECL Logic Devices

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PACKAGE DIMENSIONS

SO-8 D SUFFIX PLASTIC SOIC PACKAGE CASE 751-07 ISSUE V



NOTES:

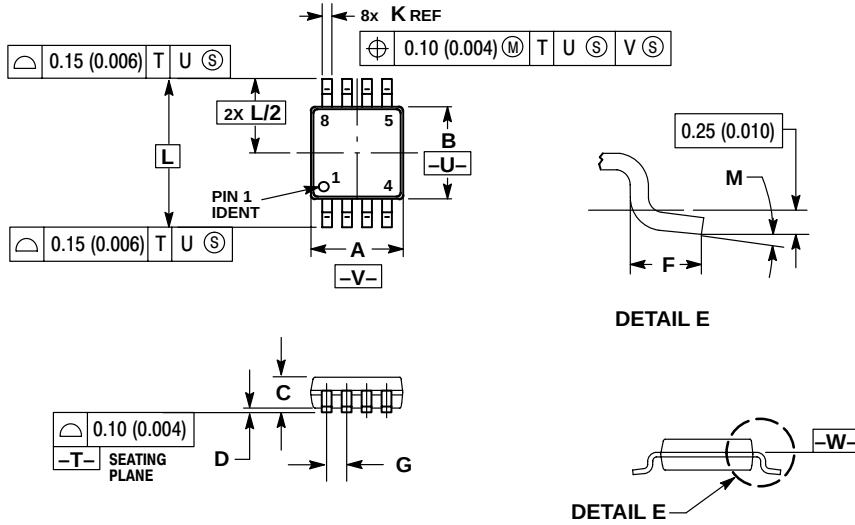
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

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PACKAGE DIMENSIONS

TSSOP-8
DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948R-02
ISSUE A



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0°	6°	0°	6°

Notes

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